

JFET Voltage-Controlled Resistors

PRODUCT SUMMARY								
Part Number	V _{GS(off)} Max (V)	V _{(BR)GSS} Min (V)	r _{DS(on)} Max (Ω)					
VCR2N	-7	-25	60					
VCR4N	-7	-25	600					
VCR7N	-5	-25	8000					

FEATURES

- Continuous Voltage-Controlled Resistance
- High Off-Isolation
- High Input Impedance

BENEFITS

- Gain Ranging Capability/Wide Range Signal Attenuation
- No Circuit Interaction
- Simplified Drive

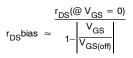
APPLICATIONS

- Variable Gain Amplifiers
- Voltage Controlled Oscillator
- AGC

DESCRIPTION

The VCR2N/4N/7N JFET voltage controlled resistors have an ac drain-source resistance that is controlled by a dc bias voltage (V_{GS}) applied to their high impedance gate terminal. Minimum r_{DS} occurs when $V_{GS} = 0$ V. As V_{GS} approaches the pinch-off voltage, r_{DS} rapidly increases. This series of junction FETs is intended for applications where the drain-source voltage is a low-level ac signal with no dc component.

Key to device performance is the predictable r_{DS} change versus V_{GS} bias where:



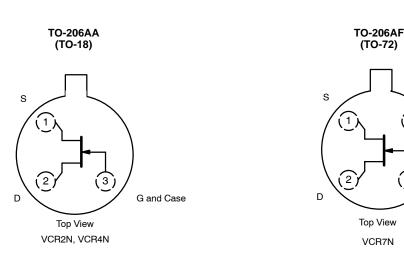
These n-channel devices feature $r_{DS(on)}$ ranging from 20 to 8000 Ω . All packages are hermetically sealed and may be processed per MIL-S-19500 (see Military Information).

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For applications information see AN105.

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ABSOLUTE MAXIMUM RATINGS^a

Gate-Source, Gate-Drain Voltage	۶V
Gate Current	nA
Power Dissipation ^b	۱W
Operating Junction Temperature Range	°C
Storage Temperature65 to 200	°C

Lead Temperature (1/16" from case for 10 sec.) 300°C

- Notes: a. $T_A = 25^{\circ}C$ unless otherwise noted.

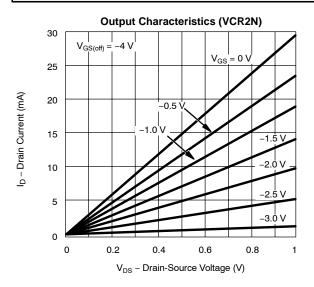
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)											
				Limits							
				VCR2N		VCR4N		VCR7N		1	
Parameter	Symbol	Test Conditions	Тур ^а	Min	Max	Min	Max	Min	Max	Unit	
Static											
Gate-Source Breakdown Voltage	V _{(BR)GSS}	I_G = -1 μ A, V_{DS} = 0 V	-55	-25		-25		-25		v	
Gate-Source Cutoff Voltage	V _{GS(off)}	V_{DS} = 10 V, I_D = 1 μ A		-3.5	-7	-3.5	-7	-2.5	-5		
Gate Reverse Current	I _{GSS}	$V_{GS} = -15 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			-5		-0.2		-0.1	nA	
Drain-Source On-Resistance	r _{DS(on)}	V_{GS} = 0 V, I_D = 10 mA		20	60					Ω	
		V_{GS} = 0 V, I_D = 1 mA				200	600				
		V_{GS} = 0 V, I_D = 0.1 mA						4000	8000		
Gate-Source Forward Voltage	V _{GS(F)}	$V_{DS} = 0 V$, $I_G = 1 mA$	0.7							V	
Dynamic					-		-		-	-	
Drain-Source On-Resistance	r _{ds(on)}	V_{GS} = 0 V, I _D = 0 mA f = 1 kHz		20	60	200	600	4000	8000	Ω	
Drain-Gate Capacitance	C _{dg}	V_{GD} = -10 V, I _S = 0 mA f = 1 MHz			7.5		3		1.5	pF	
Source-Gate Capacitance	C _{sg}	V_{GS} = -10 V, I _D = 0 mA f = 1 kHz			7.5		3		1.5	pr	

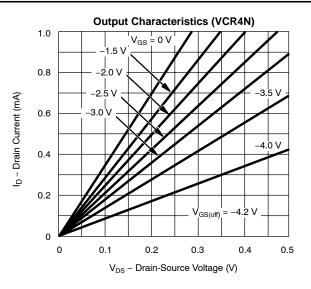
Notes:

Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. a.

NCB/NPA/NT

TYPICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)

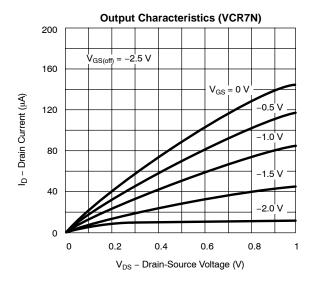






VCR2N/4N/7N Vishay Siliconix

TYPICAL CHARACTERISTICS (T_A = 25° C UNLESS OTHERWISE NOTED)



APPLICATIONS

A simple application of a FET VCR is shown in Figure 1, the circuit for a voltage divider attenuator.

The output voltage is:

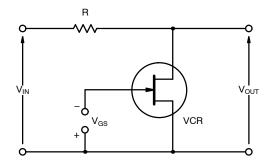


FIGURE 1. Simple Attenuator Circuit

$$V_{OUT} = \frac{V_{IN} r_{DS}}{R_{+} r_{DS}}$$

It is assumed that the output voltage is not so large as to push the VCR out of the linear resistance region, and that the r_{DS} is not shunted by the load.

The lowest value which V_{OUT} can assume is:

$$V_{OUT(min)} = \frac{V_{IN} r_{DS(on)}}{B + r_{DS(on)}}$$

Since r_{DS} can be extremely large, the highest value is:

 $V_{OUT(max)} = V_{IN}$



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